## NSN 5962-01-158-4845

Memory Microcircuit - Page 1 of 1



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Body Length:
1.220 inches
Body Width:
0.598 inches
Body Height:
0.140 inches
Operating Tempurature Range:
-0.0/+70.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and bipolar and 3-state output and programmable
Inclosure Material:
Glass and metal
Inclosure Configuration:
Dual-in-line
Output Logic Form:
P-type metal oxide-semiconductor logic
Input Circuit Pattern:
13 input
Terminal Surface Treatment:
Terminal Surface Treatment: Gold
Gold
Gold Voltage Rating And Type Per Characteristic:
Gold Voltage Rating And Type Per Characteristic: 0.03 volts power source
Gold Voltage Rating And Type Per Characteristic: 0.03 volts power source Time Rating Per Chacteristic:
Gold Voltage Rating And Type Per Characteristic: 0.03 volts power source Time Rating Per Chacteristic: 1000.00 nanoseconds propagation delay time, low to high level output
Gold Voltage Rating And Type Per Characteristic: 0.03 volts power source Time Rating Per Chacteristic: 1000.00 nanoseconds propagation delay time, low to high level output Memory Device Type:
Gold Voltage Rating And Type Per Characteristic: 0.03 volts power source Time Rating Per Chacteristic: 1000.00 nanoseconds propagation delay time, low to high level output Memory Device Type: Rom
Gold Voltage Rating And Type Per Characteristic: 0.03 volts power source Time Rating Per Chacteristic: 1000.00 nanoseconds propagation delay time, low to high level output Memory Device Type: Rom Precious Material And Location:
GoldVoltage Rating And Type Per Characteristic:0.03 volts power sourceTime Rating Per Chacteristic:1000.00 nanoseconds propagation delay time, low to high level outputMemory Device Type:RomPrecious Material And Location:Case and terminal surface gold
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GoldVoltage Rating And Type Per Characteristic:0.03 volts power sourceTime Rating Per Chacteristic:1000.00 nanoseconds propagation delay time, low to high level outputMemory Device Type:RomPrecious Material And Location:Case and terminal surface goldPrecious Material:GoldTerminal Type And Quantity:24 printed circuit
GoldVoltage Rating And Type Per Characteristic:0.03 volts power sourceTime Rating Per Chacteristic:1000.00 nanoseconds propagation delay time, low to high level outputMemory Device Type:RomPrecious Material And Location:Case and terminal surface goldPrecious Material:GoldTerminal Type And Quantity:24 printed circuitShelf Life:
Gold Voltage Rating And Type Per Characteristic: 0.03 volts power source Time Rating Per Chacteristic: 1000.00 nanoseconds propagation delay time, low to high level output Memory Device Type: Rom Precious Material And Location: Case and terminal surface gold Precious Material: Gold Terminal Type And Quantity: 24 printed circuit Shelf Life:
Gold Voltage Rating And Type Per Characteristic: 0.03 volts power source Time Rating Per Chacteristic: 1000.00 nanoseconds propagation delay time, low to high level output Memory Device Type: Rom Precious Material And Location: Case and terminal surface gold Precious Material: Gold Terminal Type And Quantity: 24 printed circuit Shelf Life:
Gold Voltage Rating And Type Per Characteristic: 0.03 volts power source Time Rating Per Chacteristic: 1000.00 nanoseconds propagation delay time, low to high level output Memory Device Type: Rom Precious Material And Location: Case and terminal surface gold Precious Material: Gold Terminal Type And Quantity: 24 printed circuit Shelf Life: N/a Unit Of Measure:
Gold Voltage Rating And Type Per Characteristic: 0.03 volts power source Time Rating Per Chacteristic: 1000.00 nanoseconds propagation delay time, low to high level output Memory Device Type: Rom Precious Material And Location: Case and terminal surface gold Precious Material: Gold Ferminal Type And Quantity: 24 printed circuit Shelf Life: N/a Unit Of Measure: Demilitarization:

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